

6. Discussion

The theoretical efficiency of 1.4 % could be achieved using BiTe modular design. There are many designs work in the range of 5 % - 10 % efficiency like, exhaust duct, Inclinator etc. Here with transformers it is very low because of low temperature difference and the less heat flux. The transformers are not moving machines and work with more than 98% efficiency in comparison with 40 % efficiency of IC engine.

Based on some valuable data on waste heat thermoelectric generators reported so far, we should discuss key issues to be solved from technical and economic points of view:

- (1) The performance of the thermoelectric materials used to build the thermoelectric generator.
- (2) The fabrication of a good electrical contact of a metal electrode to the materials, where mechanically durable properties are required against a harsh heat cycle.
- (3) The achievement of a minimum contact heat loss at the heat exchanger.

Vast quantities of untapped natural heat is available together with huge amount of waste heat, most of which is below 100C and is discharged into the environment. Thermoelectric generation is an environmentally friendly technology which can convert this unused heat, and in particular lower temperature heat, into electricity. This technology has been successfully demonstrated on a laboratory scale and in prototype commercial systems. Collaboration between University and Industry has resulted in research and development in this area of thermoelectric technology progressing rapidly.

In the near future thermoelectric waste heat recovery will make a significant contribution, over a wide range of applications, in reducing fossil fuel consumption and global warming. The price for such TE module of 1 W will be 1\$. So the payback period may be 416 days when it is continuously operating. But if we proceed with nano film / quantum well designs we can further decrease the payback period to 83 days.

7. Conclusion

Energy collection using thermoelectric effect of materials is much more cost effective, continuous method compared to conventional solar power. While the transformers in operation it continuously dissipate heat, not subjected to natural changes in the environment. No need to have exposure or large room to install a thermopile which efficiently extracts energy.

So it is the biggest challenge to design a well suited thermo element using cost effective materials even it gives a little electro motive force. When it is connected with all the fins of a transformer collectively it gives a substantial energy, which can there be stored or can use for another application at the site.

The theoretical efficiency of 1.4 % could be achieved using BiTe modular design. But many challenges still exist in the event of fixing to the transformer fin. The contact resistance would be the biggest problem. Today the thin film nano technology developed towards to the TE applications. So without pasting them on transformer fins, it is easier to fabricate the radiators with TE nano films embedded. That will drastically cut down the contact resistances and additional works involved in fixing these modules to the radiator. These panel type radiators are standard design, so one manufactured the radiator with TE coating, with some additional cost would definitely have a different market. Actually this TE conversions seems to be costly because of lees usage, but with the increase of use will definitely cut down the prices in future.



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Appendix I:

Thermoelectric Technical Reference —

Averaged Module Material Parameters at Various Temperatures


For all tables:

SM = Module Seebeck coefficient in volts/K (or volts/degreeC)

RM = Module resistance in ohms

KM = Module thermal conductance in watts/K (or watts/degreeC)

NOTE: The data on the following tables reflects effective module parameters of Ferrotec manufactured TEs, in normal ambient air using thermal grease at both the hot and cold module interfaces. Raw Bismuth Telluride semiconductor material not in module form has substantially different values for these parameters. *We do not* recommend using this data for the analysis of other manufacturer's modules.

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9-Ampere Module 15-Ampere Module

Temperature		S_M	R_M	K_M	R_M	K_M
°C	°K	V/K	ohms	w/K	ohms	w/K
-100	173.2	0.00859	0.2130	0.2103	0.1278	0.3504
-90	183.2	0.00898	0.2186	0.2086	0.1312	0.3477
-80	193.2	0.00938	0.2263	0.2056	0.1358	0.3427
-70	203.2	0.00978	0.2360	0.2018	0.1416	0.3364
-60	213.2	0.01017	0.2474	0.1976	0.1484	0.3293
-50	223.2	0.01056	0.2604	0.1933	0.1562	0.3221
-40	233.2	0.01094	0.2748	0.1892	0.1649	0.3153

-30	243.2	0.01130	0.2906	0.1857	0.1743	0.3096
-20	253.2	0.01165	0.3075	0.1831	0.1845	0.3052
-10	263.2	0.01198	0.3253	0.1816	0.1952	0.3027
0	273.2	0.01229	0.3440	0.1815	0.2064	0.3024
10	283.2	0.01257	0.3634	0.1828	0.2180	0.3047
20	293.2	0.01282	0.3833	0.1858	0.2300	0.3096
30	303.2	0.01304	0.4035	0.1905	0.2421	0.3176
40	313.2	0.01323	0.4239	0.1971	0.2544	0.3286
50	323.2	0.01337	0.4444	0.2057	0.2666	0.3428
60	333.2	0.01347	0.4647	0.2162	0.2788	0.3602
70	343.2	0.01353	0.4848	0.2286	0.2909	0.3809
80	353.2	0.01353	0.5044	0.2428	0.3026	0.4047
90	363.2	0.01349	0.5234	0.2589	0.3140	0.4316
100	373.2	0.01338	0.5417	0.2768	0.3250	0.4613
110	383.2	0.01322	0.5590	0.2961	0.3354	0.4936
120	393.2	0.01300	0.5753	0.3169	0.3452	0.5282
130	403.2	0.01271	0.5904	0.3389	0.3542	0.5649
140	413.2	0.01235	0.6041	0.3619	0.3624	0.6032
150	423.2	0.01192	0.6162	0.3856	0.3697	0.6426



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71-Couple Modules

Temperature		4-Ampere Module			6-Ampere Module	
		S_M	R_M	K_M	R_M	K_M
$^{\circ}C$	$^{\circ}K$	V/K	ohms	w/K	ohms	w/K
-100	173.2	0.01968	1.0980	0.2140	0.7318	0.3210
-90	183.2	0.02058	1.1270	0.2123	0.7511	0.3185
-80	193.2	0.02148	1.1663	0.2093	0.7775	0.3140
-70	203.2	0.02239	1.2159	0.2054	0.8106	0.3082
-60	213.2	0.02329	1.2746	0.2011	0.8498	0.3017
-50	223.2	0.02418	1.3417	0.1967	0.8945	0.2951
-40	233.2	0.02505	1.4162	0.1926	0.9441	0.2889
-30	243.2	0.02588	1.4974	0.1891	0.9983	0.2836
-20	253.2	0.02668	1.5844	0.1864	1.0563	0.2796
-10	263.2	0.02744	1.6766	0.1849	1.1177	0.2773
0	273.2	0.02814	1.7729	0.1847	1.1819	0.2771
10	283.2	0.02879	1.8727	0.1861	1.2485	0.2791
20	293.2	0.02937	1.9751	0.1891	1.3167	0.2837
30	303.2	0.02987	2.0793	0.1939	1.3862	0.2909
40	313.2	0.03029	2.1845	0.2007	1.4564	0.3010
50	323.2	0.03062	2.2899	0.2094	1.5266	0.3140
60	333.2	0.03085	2.3947	0.2200	1.5965	0.3300



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70	343.2	0.03098	2.4980	0.2326	1.6654	0.3490
80	353.2	0.03100	2.5991	0.2472	1.7327	0.3708
90	363.2	0.03089	2.6971	0.2636	1.7981	0.3954
100	373.2	0.03066	2.7913	0.2817	1.8608	0.4226
110	383.2	0.03029	2.8807	0.3015	1.9205	0.4522
120	393.2	0.02977	2.9647	0.3226	1.9765	0.4839
130	403.2	0.02911	3.0423	0.3450	2.0282	0.5175
140	413.2	0.02828	3.1129	0.3684	2.0753	0.5526
150	423.2	0.02729	3.1755	0.3925	2.1170	0.5887

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Temperature		4-Ampere Module			6-Ampere Module	
		S_M	R_M	K_M	R_M	K_M
$^{\circ}C$	$^{\circ}K$	V/K	ohms	w/K	ohms	w/K
-100	173.2	0.03520	1.9634	0.3828	1.3089	0.5742
-90	183.2	0.03680	2.0152	0.3798	1.3435	0.5697
-80	193.2	0.03843	2.0862	0.3744	1.3908	0.5616
-70	203.2	0.04005	2.1749	0.3675	1.4500	0.5512
-60	213.2	0.04166	2.2800	0.3597	1.5200	0.5396
-50	223.2	0.04325	0.3999	0.3519	1.6000	0.5278

-40	233.2	0.04480	2.5332	0.3445	1.6888	0.5168
-30	243.2	0.04630	2.6784	0.3382	1.7856	0.5073
-20	253.2	0.04773	2.8341	0.3335	1.8894	0.5002
-10	263.2	0.04908	2.9989	0.3307	1.9993	0.4961
0	273.2	0.05034	3.1713	0.3304	2.1142	0.4956
10	283.2	0.05150	3.3498	0.3328	2.2332	0.4992
20	293.2	0.05253	3.5329	0.3383	2.3553	0.5074
30	303.2	0.05343	3.7193	0.3469	2.4796	0.5204
40	313.2	0.05418	3.9075	0.3590	2.6050	0.5384
50	323.2	0.05477	4.0961	0.3745	2.7307	0.5617
60	333.2	0.05519	4.2835	0.3936	2.8556	0.5903
70	343.2	0.05542	4.4683	0.4161	2.9789	0.6242
80	353.2	0.05544	4.6491	0.4422	3.0994	0.6632
90	363.2	0.05525	4.8244	0.4715	3.2163	0.7072
100	373.2	0.05483	4.9928	0.5039	3.3285	0.7559
110	383.2	0.05417	5.1528	0.5392	3.4352	0.8088
120	393.2	0.05325	5.3030	0.5771	3.5354	0.8656
130	403.2	0.05206	5.4419	0.6171	3.6280	0.9257
140	413.2	0.05059	5.5681	0.6589	3.7121	0.9884
150	423.2	0.04882	5.6801	0.7021	3.7867	1.0531



Appendix II :

Specification of step up transformer

You can count on our quality

Products

- Power transformers from 5 to 100 MVA up to Um 170 KV
- ONAN / ONAF / OFWF
- 16 2/3 Hz / 50 Hz / 60 Hz
- Oil chokes
- Neutral electromagnetic coupler
- Earthing transformers and Peterson coils
- Single phase transformers
- Resonant circuit reactances
- Coupling transformers and reactors for ripple control
- Shunt reactors and current limiting reactors
- Transformers with line drop and parallel regulation
- Rectifier and furnace transformers

Repair

- All types of transformers < 5 MVA
- Manufacture of complete spare parts

Maintenance

Provider of services for everything to do with transformers

Quality management

The complete operational process is controlled by a tried and tested quality management system

The SGB Group is certified in accordance with

- ISO 9001
- Federal railways welding authorisation
- KTA 1401

Markets

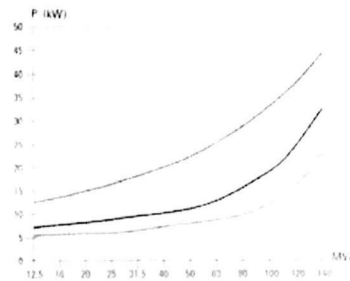
The SGB group manufactures and tests transformers for the world market.

We comply with the standards of

- DIN / VDE
- IEC 76
- British standard
- ANSI / IEEE
- CAN / CSA
- NEMA
- and others
- UL
- ENEL
- ÖVE
- SVV
- UNE
- NF

No-load losses / Noise

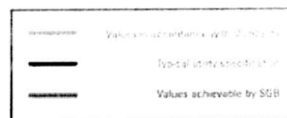
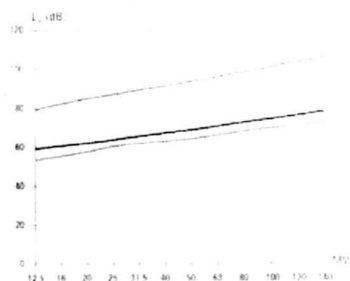
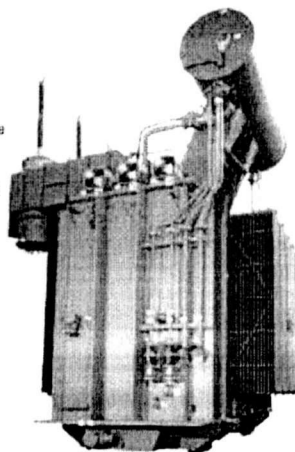
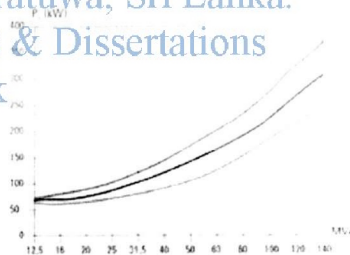
Up to the minute core-laying technology (step lap) and the application of high quality, extremely low loss sheet steel with low magnetism, guarantees the customer low no-load losses and noise emissions.



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Short-circuit losses

Thanks to the application of the conductor cross sections, low-load losses can be achieved in relation to the additional losses. As a result, SGB transformers completely meet the technical as well as the economical requirements with regard to short circuit proofing.



Appendix III :

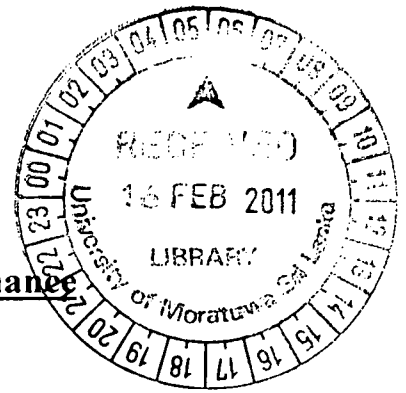
Spreadsheet Calculation of p-Type Element Performance

T (C)	Material	T (K)	α ($\mu\text{V/K}$)	ρ ($10^{-3} \Omega \text{ cm}$)	κ (mW/cm K)	zT	Max Red Eff (%)	s (1/V)	u (1/V)	Red Eff (%)	$u \kappa dT$ (A/cm)	$I(x)$ (A/cm)	Φ (V)	Efficiency (%)
700	CeFe ₄ Sb ₁₂	973	156	0.849	26.89	1.04	17.62	2.82	3.6179	16.70	2.4457	0.00	0.42833	
675	CeFe ₄ Sb ₁₂	948	160	0.842	26.98	1.07	18.04	2.89	3.6457	17.36	2.4668	2.45	0.42643	0.44
650	CeFe ₄ Sb ₁₂	923	164	0.834	27.06	1.09	18.27	2.96	3.6573	17.62	2.4668	4.91	0.42443	0.91
625	CeFe ₄ Sb ₁₂	898	166	0.826	27.12	1.10	18.34	3.02	3.6551	17.81	2.4763	7.39	0.42237	1.39
600	CeFe ₄ Sb ₁₂	873	167	0.818	27.17	1.09	18.26	3.07	3.6413	17.84	2.4757	9.86	0.42024	1.89
575	CeFe ₄ Sb ₁₂	848	167	0.809	27.20	1.08	18.06	3.11	3.6184	17.74	2.4668	12.33	0.41807	2.39
550	CeFe ₄ Sb ₁₂	823	167	0.800	27.22	1.05	17.75	3.15	3.5884	17.52	2.4512	14.78	0.41588	2.91
525	CeFe ₄ Sb ₁₂	798	166	0.791	27.23	1.02	17.36	3.18	3.5533	17.19	2.4303	17.21	0.41366	3.43
500	CeFe ₄ Sb ₁₂	773	164	0.782	27.23	0.98	16.89	3.20	3.5146	16.78	2.4056	19.62	0.41143	3.95
475	CeFe ₄ Sb ₁₂	748	162	0.772	27.22	0.94	16.37	3.23	3.4737	16.30	2.3781	22.00	0.40921	4.46
450	CeFe ₄ Sb ₁₂	723	160	0.762	27.21	0.89	15.79	3.25	3.4317	15.76	2.3490	24.35	0.40699	4.98
425	CeFe ₄ Sb ₁₂	698	157	0.752	27.19	0.84	15.18	3.26	3.3893	15.16	2.3189	26.66	0.40479	5.50
400	CeFe ₄ Sb ₁₂	673	154	0.741	27.16	0.80	14.54	3.28	3.3474	14.53	2.2885	28.95	0.40261	6.01
375	Zn ₄ Sb ₃	648	200	3.118	6.37	1.35	21.04	3.97	3.7279	30.99	0	38.95	0.40261	6.01
350	Zn ₄ Sb ₃	623	195	3.064	6.37	1.27	20.18	3.98	3.6651	26.09	0.5889	29.54	0.39950	6.73
325	Zn ₄ Sb ₃	598	191	3.008	6.32	1.20	19.45	4.05	3.6063	19.28	0.5768	30.12	0.39643	7.45
300	Zn ₄ Sb ₃	573	187	2.949	6.22	1.14	18.78	4.18	3.5512	18.51	0.5607	30.68	0.39338	8.16
275	Zn ₄ Sb ₃	548	182	2.889	6.10	1.08	18.13	4.24	3.4991	17.73	0.5430	31.22	0.39035	8.87
250	Zn ₄ Sb ₃	523	178	2.825	6.00	1.02	17.43	4.32	3.4498	16.89	0.5257	31.75	0.38736	9.57
225	Zn ₄ Sb ₃	498	173	2.760	5.93	0.96	16.64	4.41	3.4028	15.98	0.5107	32.26	0.38441	10.25
200	Zn ₄ Sb ₃	473	168	2.691	5.91	0.88	15.71	4.45	3.3576	14.56	0.4999	32.76	0.38151	10.93
175	p-Bi ₂ Te ₃	448	165	2.645	5.93	0.83	15.02	4.45	3.3295	14.26	0.3167	33.08	0.37970	11.35
150	p-Bi ₂ Te ₃	423	196	2.225	10.71	0.78	14.31	3.52	3.5079	14.31	0	33.68	0.37970	11.35
125	p-Bi ₂ Te ₃	398	198	2.174	10.43	0.82	14.86	3.72	3.5107	14.83	0.3339	33.41	0.37866	11.60
100	p-Bi ₂ Te ₃	373	202	2.016	9.92	0.92	16.14	4.28	3.5109	15.77	0.8932	34.30	0.37551	12.33
75	p-Bi ₂ Te ₃	348	204	1.834	9.71	0.99	17.03	4.75	3.4999	16.12	0.8603	35.16	0.37209	13.13
50	p-Bi ₂ Te ₃	323	203	1.632	9.70	1.04	17.64	5.29	3.4783	16.02	0.8466	35.01	0.36846	13.9
25	p-Bi ₂ Te ₃	298	201	1.415	9.79	1.08	18.06	5.92	3.4474	15.58	0.8435	35.85	0.36471	14.95
0	p-Bi ₂ Te ₃	273	194	1.198	9.87	1.11	18.41	6.69	3.4685	14.81	0.8424	37.70	0.36089	15.75
		248	185	1.015	9.95	1.11	18.40	7.55	3.4633	13.69	0.8350	38.53	0.35708	16.89
		223	173	0.927	9.83	1.00	17.14	8.02	3.3128	12.09	0.8132	39.34	0.35341	17.49

α , ρ , κ are the measured material properties. zT , the maximum reduced efficiency, and s are calculated from Equation 9.15, Equation 9.20, and Equation 9.18. The calculation uses $u_0 = 3.6179 \text{ V}^{-1}$ as a starting value for u . The subsequent values of u use $\frac{1}{u} = \frac{1}{u_0} \sqrt{1 - 2u_0^2 \left(\frac{\rho_0 \kappa_0 + \rho_0 \kappa_0}{2} \right) (T_0 - T_{\infty})} - \frac{1}{u_0} \left(\frac{\rho_0 \kappa_0 + \rho_0 \kappa_0}{2} \right) \rho_0 \kappa_0$ following Equation 9.20. The reduced efficiency is given by Equation 9.15, the maximum reduced efficiency ($u = s$, infinitely aged), by Equation 9.20. The column $u \kappa dT$ is used to find the physical length of each interval. Specifically, $(u \kappa dT)_0$ is given by Equation 9.21. Efficiency is the single element efficiency, including Carnot, Equation 9.35 from the hot end 1700°C to the point in question. The thermoelectric potential (voltage), V , is given by Equation 9.35 from the hot end 1700°C to the point in question.

Appendix IV :

Spreadsheet Calculation of n-Type Element Performance



Material	T (K)	α ($\mu\text{V/K}$)	ρ ($10^{-3} \Omega \cdot \text{cm}$)	κ (mW/cm K)	z	Max Rec Eff (%)	s (UV)	u (UV)	Red Eff (%)	used [†] (A/cm)	$J(z)$ (A/cm)	Φ (V)	Efficiency (%)
Metal	975	0	0.0200	1190	0.60	0.00	0.00	-1.8558	-7.99	-2.2062	0.00	-0.53886	-0.01
Metal	974	0	0.0200	1188	0.60	0.00	0.00	-1.8556	-7.97	0	-2.21	-0.53891	-0.01
Contact	974	0	10.000	0.00258	0.60	0.00	0.00	-1.8556	-7.97	0	-2.21	-0.53891	-0.01
Contact	973	0	10.000	0.00257	0.60	0.00	0.00	-1.8555	-7.95	-4.41 $\times 10^{-6}$	-2.21	-0.53895	-0.02
n-CoSb ₃	973	-186	0.981	42.74	0.60	14.62	-1.39	-2.7929	12.43	0	-2.21	-0.53895	-0.02
n-CoSb ₃	948	-188	0.985	41.86	0.62	14.80	-1.95	-2.7886	12.95	-2.5512	-5.16	-0.53715	0.32
n-CoSb ₃	923	-191	0.983	41.02	0.63	14.95	-2.00	-2.7828	13.41	-2.8861	-8.04	-0.53526	0.67
n-CoSb ₃	898	-193	0.991	40.24	0.64	15.07	-2.05	-2.7754	13.86	-2.8229	-10.87	-0.53265	1.04
n-CoSb ₃	873	-194	0.992	39.50	0.64	15.14	-2.10	-2.7686	14.12	-2.7621	-13.63	-0.53115	1.43
n-CoSb ₃	848	-196	0.993	38.83	0.64	15.17	-2.15	-2.7600	14.36	-2.7040	-16.33	-0.52895	1.84
n-CoSb ₃	823	-197	0.993	38.23	0.64	15.15	-2.20	-2.7437	14.52	-2.6451	-18.98	-0.52667	2.26
n-CoSb ₃	798	-198	0.992	37.71	0.64	15.08	-2.25	-2.7266	14.59	-2.5979	-21.58	-0.52431	2.70
n-CoSb ₃	773	-198	0.989	37.27	0.63	14.94	-2.29	-2.7137	14.57	-2.5509	-24.13	-0.52183	3.15
n-CoSb ₃	748	-198	0.985	36.83	0.61	14.73	-2.33	-2.6959	14.46	-2.5086	-26.64	-0.51949	3.61
n-CoSb ₃	723	-198	0.979	36.68	0.59	14.45	-2.36	-2.6782	14.26	-2.4715	-29.11	-0.51687	4.03
n-CoSb ₃	698	-197	0.972	36.55	0.56	14.09	-2.38	-2.6606	13.95	-2.4401	-31.55	-0.51431	4.56
n-CoSb ₃	673	-196	0.963	36.54	0.53	13.65	-2.40	-2.6312	13.56	-2.4147	-33.97	-0.51174	5.03
n-CoSb ₃	648	-194	0.952	36.65	0.50	13.13	-2.41	-2.6061	13.07	-2.3956	-36.36	-0.50913	5.51
n-CoSb ₃	623	-191	0.939	36.89	0.46	12.54	-2.41	-2.5794	12.45	-2.3832	-38.74	-0.50663	5.94
n-CoSb ₃	598	-188	0.924	37.25	0.41	11.87	-2.40	-2.5514	11.83	-2.3774	-41.12	-0.50412	6.45
n-CoSb ₃	573	-184	0.907	37.75	0.36	11.13	-2.38	-2.5222	11.16	-2.3783	-43.50	-0.50165	6.90
n-CoSb ₃	548	-179	0.883	38.37	0.31	10.34	-2.35	-2.4921	10.31	-2.3855	-45.89	-0.49923	7.34
n-CoSb ₃	523	-174	0.867	39.10	0.26	9.51	-2.32	-2.4617	9.48	-2.3984	-48.28	-0.49699	7.77
n-CoSb ₃	498	-168	0.845	39.52	0.21	8.65	-2.27	-2.4313	8.62	-2.4164	-50.70	-0.49480	8.14
n-CoSb ₃	473	-161	0.822	40.82	0.17	7.80	-2.22	-2.4014	7.75	-2.4387	-53.14	-0.49271	8.56
n-CoSb ₃	448	-155	0.799	41.79	0.12	6.95	-2.16	-2.3725	6.89	-2.4649	-55.60	-0.49079	8.92
n-CoSb ₃	440	-153	0.791	42.12	0.11	6.69	-2.13	-2.3637	6.62	-0.7948	-56.40	-0.49019	9.03
Metal	440	0	0.0200	537	0.60	0.00	0.00	-2.6400	-1.97	0	-56.40	-0.49019	9.03
Metal	439	0	0.0200	536	0.60	0.00	0.00	-2.6399	-1.96	-1.6378	-57.49	-0.49021	9.03
Contact	439	0	10.000	0.00107	0.60	0.00	0.00	-2.6399	-1.96	0	-57.49	-0.49021	9.03
Contact	438	0	10.000	0.00107	0.60	0.00	0.00	-2.6398	-1.95	-2.18 $\times 10^{-6}$	-57.49	-0.49024	9.02
n-Bi ₂ Te ₃	438	-161	2.88	12.78	0.1	6.68	-2.03	-2.3816	6.51	0	-57.49	-0.49024	9.02
n-Bi ₂ Te ₃	423	-171	2.92	12.07	0.15	7.52	-2.15	-2.3999	7.49	-0.4454	-57.94	-0.48963	9.25
n-Bi ₂ Te ₃	398	-187	2.94	13.92	0.4	9.02	-2.36	-2.4272	8.96	-0.6933	-58.63	-0.48857	9.70

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